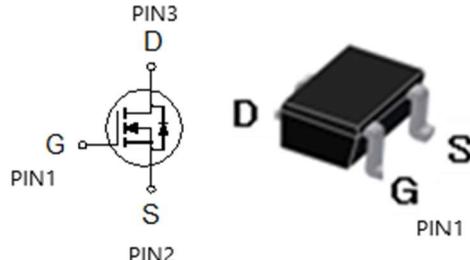


N-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

$BV_{DSS}$	30V
$R_{DS(on)}$ (MAX.)	35m $\Omega$
$I_D$	5A



N Channel MOSFET

Pb-Free Lead Plating & Halogen Free

**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS	SYMBOL	LIMITS	UNIT
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	5	A
		3.3	
Pulsed Drain Current <sup>1</sup>	$I_{DM}$	20	
Power Dissipation	$P_D$	1.25	W
		0.8	
Operating Junction & Storage Temperature Range	$T_j, T_{stg}$	-55 to 150	°C

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Ambient <sup>3</sup>	$R_{\theta JA}$		100	°C / W
Junction-to-Lead <sup>4</sup>	$R_{\theta JL}$		55	

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle  $\leq 1\%$

<sup>3</sup>100°C / W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

<sup>4</sup>  $R_{\theta JA}$  is the sum of the thermal impedance from junction to lead  $R_{\theta JL}$  and lead to ambient.

ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$	30			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 250\mu\text{A}$	1.0	1.5	3.0	
Gate-Body Leakage	$I_{\text{GSS}}$	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 20\text{V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}} = 24\text{V}, V_{\text{GS}} = 0\text{V}$			1	$\mu\text{A}$
		$V_{\text{DS}} = 20\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 125^\circ\text{C}$			10	
On-State Drain Current <sup>1</sup>	$I_{\text{D}(\text{ON})}$	$V_{\text{DS}} = 5\text{V}, V_{\text{GS}} = 10\text{V}$	5			A
Drain-Source On-State Resistance <sup>1</sup>	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}} = 10\text{V}, I_D = 5\text{A}$		30	35	$\text{m}\Omega$
		$V_{\text{GS}} = 4.5\text{V}, I_D = 4\text{A}$		40	50	
Forward Transconductance <sup>1</sup>	$g_{\text{fs}}$	$V_{\text{DS}} = 5\text{V}, I_D = 5\text{A}$		11		S
DYNAMIC						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 10\text{V}, f = 1\text{MHz}$		323		$\text{pF}$
Output Capacitance	$C_{\text{oss}}$			75		
Reverse Transfer Capacitance	$C_{\text{rss}}$			53		
Total Gate Charge <sup>1,2</sup>	$Q_g$	$V_{\text{DS}} = 10\text{V}, V_{\text{GS}} = 10\text{V}, I_D = 5\text{A}$		7.1		$\text{nC}$
Gate-Source Charge <sup>1,2</sup>	$Q_{\text{gs}}$			1.1		
Gate-Drain Charge <sup>1,2</sup>	$Q_{\text{gd}}$			2.2		
Turn-On Delay Time <sup>1,2</sup>	$t_{\text{d}(\text{on})}$	$V_{\text{DS}} = 15\text{V}, I_D = 1\text{A}, V_{\text{GS}} = 10\text{V}, R_{\text{GS}} = 6\Omega$		8		$\text{nS}$
Rise Time <sup>1,2</sup>	$t_r$			12		
Turn-Off Delay Time <sup>1,2</sup>	$t_{\text{d}(\text{off})}$			28		
Fall Time <sup>1,2</sup>	$t_f$			15		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ )						
Continuous Current	$I_s$				2	A
Pulsed Current <sup>3</sup>	$I_{\text{SM}}$				8	
Forward Voltage <sup>1</sup>	$V_{\text{SD}}$	$I_F = I_s, V_{\text{GS}} = 0\text{V}$			1.2	V

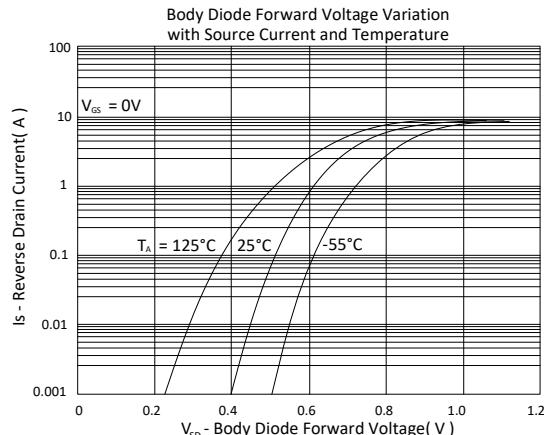
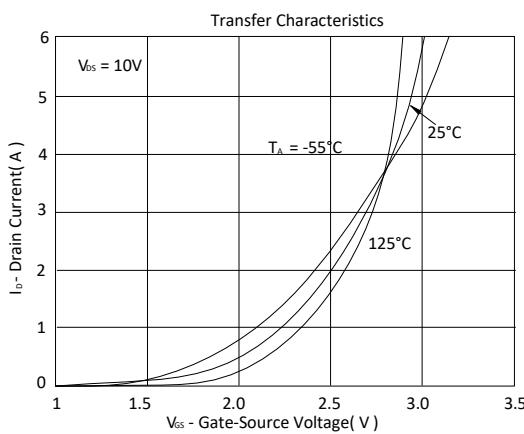
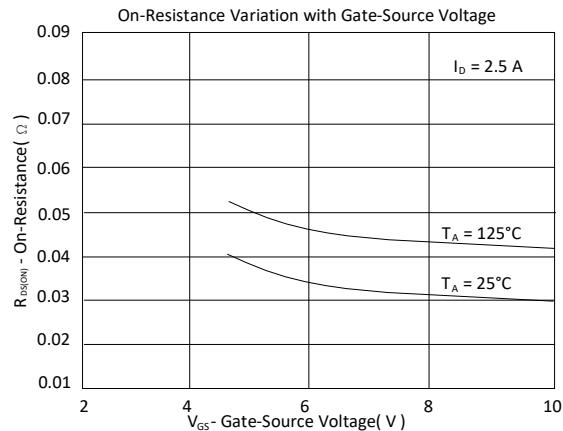
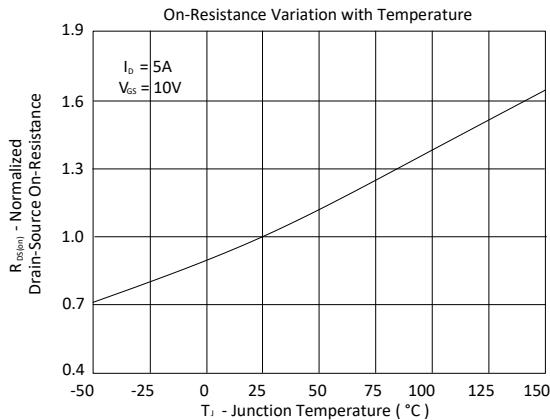
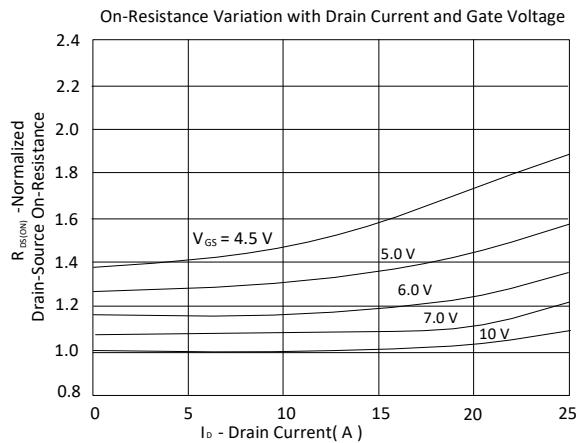
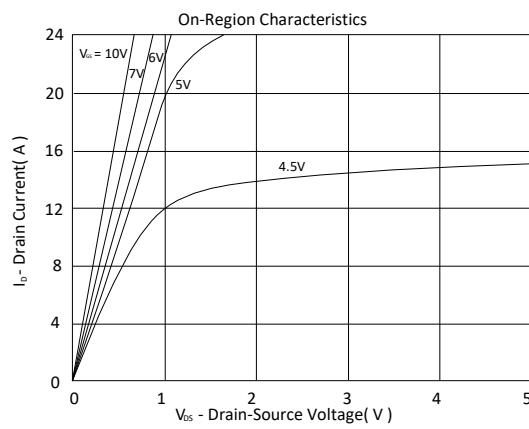
<sup>1</sup>Pulse test : Pulse Width  $\leq 300 \mu\text{sec}$ , Duty Cycle  $\leq 2\%$ .

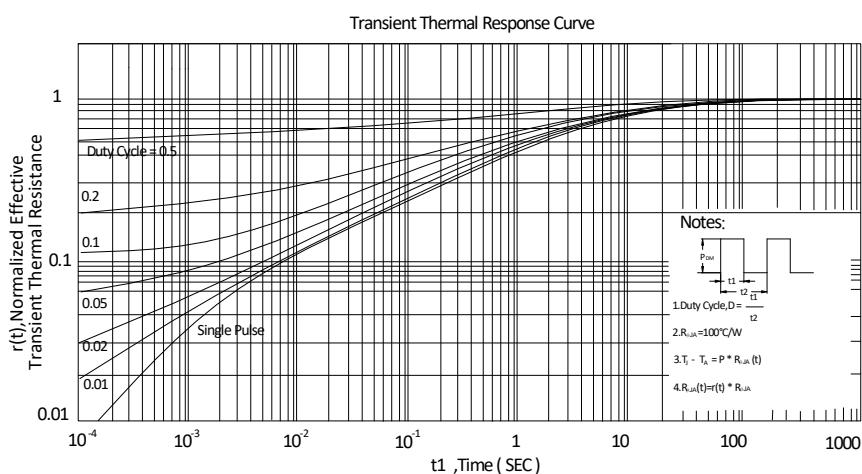
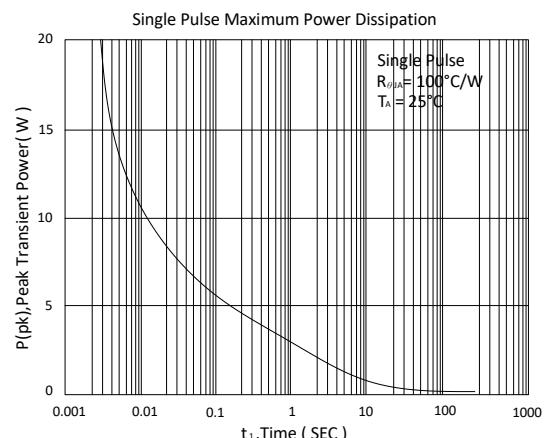
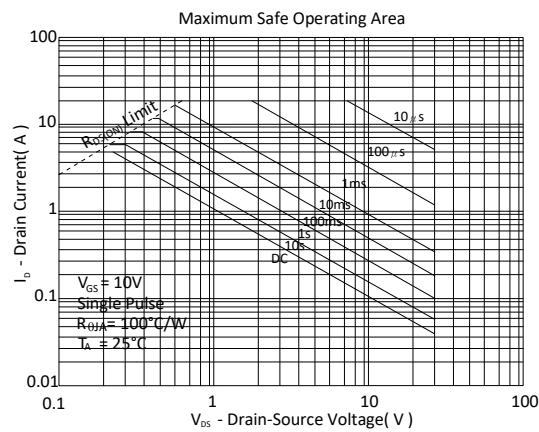
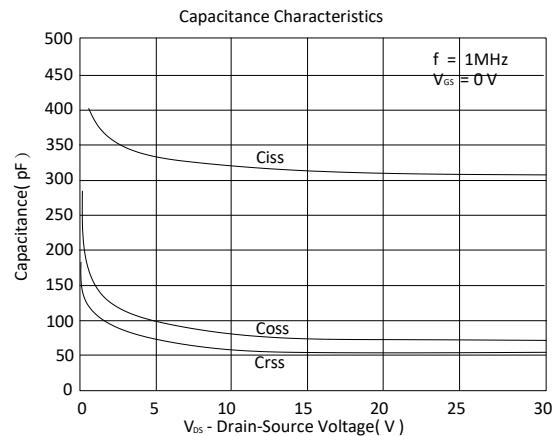
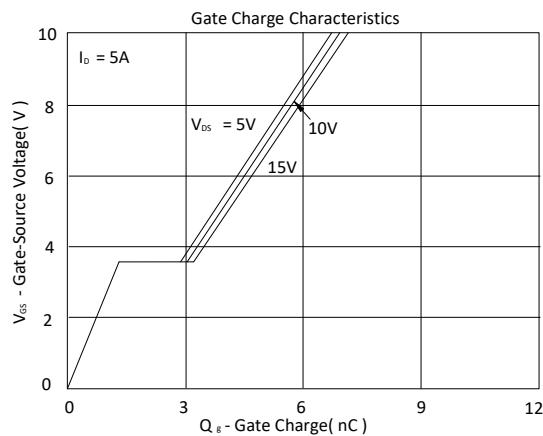
<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

EMC will review datasheet by quarter, and update new version.

### TYPICAL CHARACTERISTICS



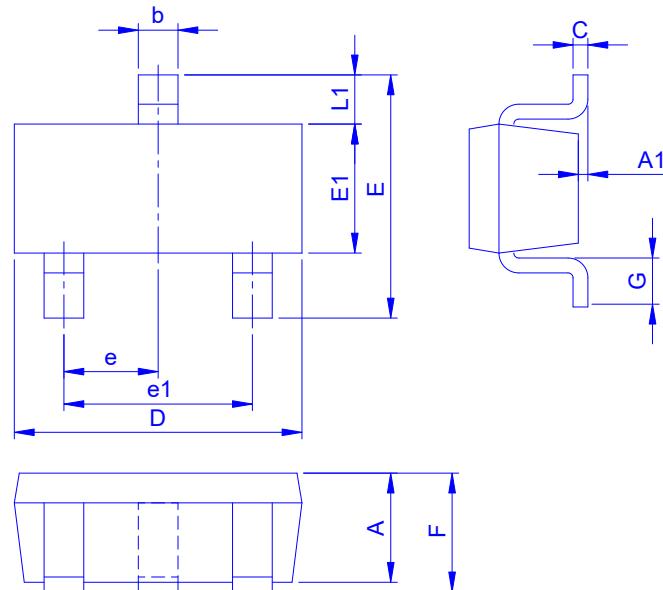


Ordering & Marking Information:

Device Name: EMB32N03J for SOT23-3



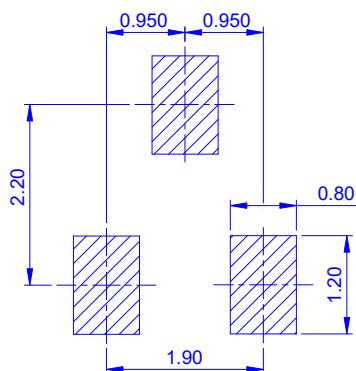
Outline Drawing



Dimension in mm

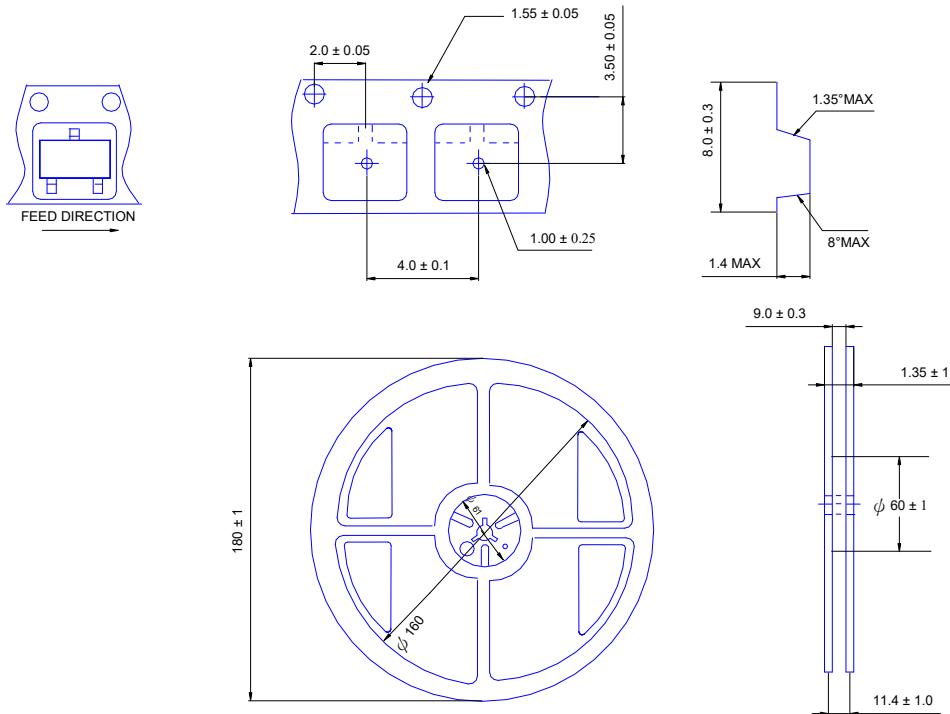
Dimension	A	A1	b	C	D	E	E1	e	e1	F	G	L1
Min.	0.70	-	0.30	0.080	2.80	2.10	1.20	0.90	1.80	0.80	0.30	0.54
Typ.	0.95	-	0.40	0.127	2.90	2.50	1.30	0.95	1.90	0.95	0.40	0.57
Max.	1.20	0.15	0.50	0.202	3.10	3.00	1.80	1.00	2.00	1.25	0.60	0.70

Footprint





◆ Tape&Reel Information:3000pcs/Reel



產品別	SOT23-3
Reel 尺寸	7"
編帶方式	FEED DIRECTION  
前空格	50
後空格	50
裝箱數	
滿捲數量	3K
捲/內盒比	5 : 1
內盒滿箱數	15K
內/外箱比	12 : 1
外箱滿箱數	180K